

## SCHMITT INVERTER

The KIC7S14FU is a high speed C<sup>2</sup>MOS SCHMITT INVERTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves a high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation.

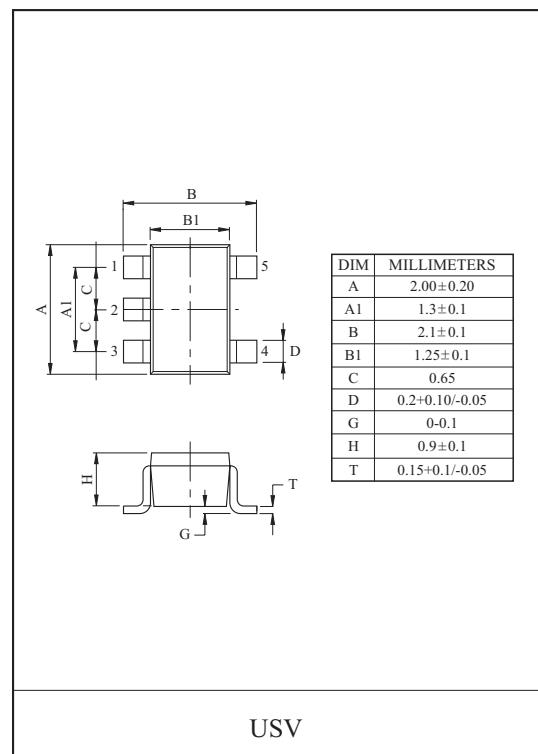
Pin Configuration and function are the same as the KIC7SU04FU but input have 25% V<sub>CC</sub> hysteresis and with its schmitt trigger function, the KIC7S14FU can be used as line receivers which will receive slow input signal. Input is equipped with protection circuits against static discharge or transient excess voltage.

## FEATURES

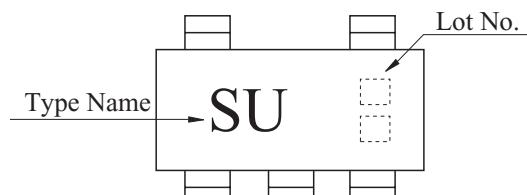
- High Speed : t<sub>pd</sub>=11ns(Typ.) at V<sub>CC</sub>=5V.
- Low Power Dissipation : I<sub>CC</sub>=1 μA(Max.) at Ta=25°C.
- High Noise Immunity : V<sub>H</sub>=1.1V at V<sub>CC</sub>=5V.
- Output Drive Capability : 5 LSTTL Loads.
- Symmetrical Output Impedance : |I<sub>OH</sub>|=I<sub>OL</sub>=2mA.
- Balanced Propagation Delays : t<sub>pLH</sub>=t<sub>pHL</sub>
- Wide Operating Voltage Range : V<sub>CC(opr)</sub>=2~6V.

## MAXIMUM RATINGS (Ta=25°C)

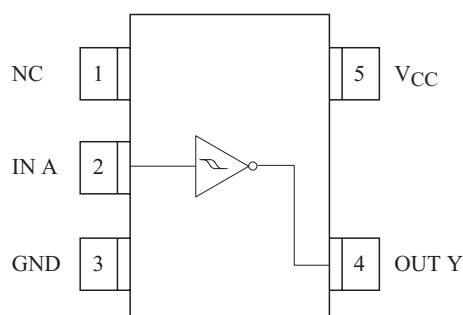
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V <sub>CC</sub>	-0.5~7	V
DC Input Voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> +0.5	V
DC Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> +0.5	V
Input Diode Current	I <sub>IK</sub>	±20	mA
Output Diode Current	I <sub>OK</sub>	±20	mA
DC Output Current	I <sub>OUT</sub>	±12.5	mA
DC V <sub>CC</sub> /Ground Current	I <sub>CC</sub>	±50	mA
Power Dissipation	P <sub>D</sub>	200	mW
Storage Temperature	T <sub>stg</sub>	-65~150	
Lead Temperature (10s)	T <sub>L</sub>	260	



## MARKING

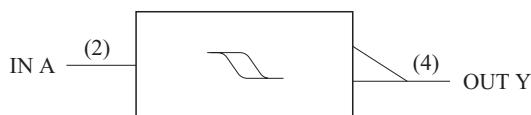


## PIN CONNECTION (TOP VIEW)



# KIC7S14FU

## LOGIC DIAGRAM



## TRUTH TABLE

A	Y
L	H
H	L

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	2 6	V
Input Voltage	V <sub>IN</sub>	0 V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0 V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	-40 85	

## DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta=25				Ta=-40 85		UNIT
			V <sub>CC</sub>	MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	
Positive Threshold Voltage	V <sub>P</sub>	-	2.0	1.0	1.25	1.5	1.0	1.5		V
			4.5	2.3	2.7	3.15	2.3	3.15		
			6.0	3.0	3.5	4.2	3.0	4.2		
Negative Threshold Voltage	V <sub>N</sub>	-	2.0	0.3	0.65	0.9	0.3	0.9		V
			4.5	1.13	1.6	2.0	1.13	2.0		
			6.0	1.5	2.3	2.6	1.5	2.6		
Hysteresis Voltage	V <sub>H</sub>	-	2.0	0.3	0.6	1.0	0.3	1.0		V
			4.5	0.6	1.1	1.4	0.6	1.4		
			6.0	0.8	1.2	1.7	0.8	1.7		
High-Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> =V <sub>IL</sub>	I <sub>OH</sub> =-20 µA	2.0	1.9	2.0	-	1.9	-	V
				4.5	4.4	4.5	-	4.4	-	
				6.0	5.9	6.0	-	5.9	-	
			I <sub>OH</sub> =-2mA I <sub>OH</sub> =-2.6mA	4.5	4.18	4.31	-	4.13	-	
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OL</sub> =20 µA	2.0	-	0.0	0.1	-	0.1	V
				4.5	-	0.0	0.1	-	0.1	
				6.0	-	0.0	0.1	-	0.1	
			I <sub>OL</sub> =2mA I <sub>OL</sub> =2.6mA	4.5	-	0.17	0.26	-	0.33	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0	-	-	± 0.1	-	± 1.0		µA
	I <sub>CC</sub>	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0	-	-	1.0	-	10.0		

# KIC7S14FU

AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub>=15pF, V<sub>CC</sub>=5V, Ta=25 )

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta=25			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>	-	-	4	8	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>	-	-	11	21	ns

AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub>=50pF, Input t<sub>r</sub>=t<sub>f</sub>=6ns)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>CC</sub>	Ta=25			Ta=-40 85		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>	-	2.0	-	50	125	-	145	ns
			4.5	-	14	25	-	30	
			6.0	-	12	21	-	24	
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>	-	2.0	-	48	100	-	235	ns
			4.5	-	12	20	-	48	
			6.0	-	9	17	-	40	
Input Capacitance	C <sub>IN</sub>	-	-	-	5	10	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 1)	-	28	-	-	-	-	

Note 1 : C<sub>PD</sub> is defined as the value of internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation : I<sub>CC(opr)</sub>=C<sub>PD</sub> · V<sub>CC</sub> · f<sub>IN</sub> + I<sub>CC</sub>